## NSN 5961-01-117-8263

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View Online at https://aerobasegroup.com/nsn/5961-01-117-8263

Inclosure Material:
Metal
Overall Length:
0.900 inches
Overall Height:
0.225 inches
Overall Width:
0.405 inches
End Application:
An/apx-76b
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Base
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
65.0 collector to base voltage/static/emitter open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 3.5
emitter to base voltage, static, collector open
Current Rating Per Characteristic:
5.00 milliamperes zero-gate-voltage source current preset and 12.50 milliamperes zero-gate-voltage source current minor
Power Rating Per Characteristic:
750.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
120.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Flange, base and leads plated; cap plating option gold
Precious Material:
Gold
Test Data Document:
80249-911319 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)

N/a

Shelf Life:

**Terminal Type And Quantity:** 

1 case and 2 ribbon

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Demilitarization:

No

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